

Analog IC Design: Assignment-2

Spring 2026, IIIT Hyderabad

Name: _____ Roll No: _____

Due Date: February 23, 2026 (18:00 hrs)

Instructions

- Technology: 180 nm SCL technology file.
 - Content: Schematics, netlists, annotated waveforms, and inference/discussion are required for each solution.
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Question 1: n-channel MOSFET Characteristics

Considering $V_{DS} = 1V$ and $\frac{W}{L} = \frac{500n}{180n}$:

(a) I_D vs V_{GS} and g_m vs V_{GS} Plots

Cases: (i) $V_{SB} = 0V$, (ii) $V_{SB} = 0.9V$, (iii) $V_{SB} = -0.9V$.

Schematic and Simulation Setup

[Insert Schematic Here]

Simulation Results (Plots)

[Insert super-imposed I_D vs V_{GS} plot here] [Insert super-imposed g_m vs V_{GS} plot here]

Discussion

Discussion:

(b) Reference Current I_{D0}

For $V_{SB} = 0V$ and $V_{GS} = 0.9V$:

- $I_{D0} = \underline{\hspace{2cm}}$

(c) g_m Variation for $V_{GS} = 0.9V$

- Case $V_{SB} = 0.9V$: Variation =
- Case $V_{SB} = -0.9V$: Variation =

(d) g_m Variation for $I_D = I_{D0}$

- Case $V_{SB} = 0.9V$: Variation =
- Case $V_{SB} = -0.9V$: Variation =

Question 2: Transconductance Analysis

Using the circuit in Figure 1 with $V_{DD} = 1.8V$.

(a) g_m vs I_D Curve

Sweep I_D from $10\ \mu A$ to $1mA$ for: 1. $(W/L) = \frac{3\ \mu m}{1\ \mu m}$ 2. $(W/L) = \frac{0.45\ \mu m}{0.18\ \mu m}$

[Insert super-imposed g_m vs I_D plot here]

Inference: Which case is closer to the expected form $g_m = \frac{2I_D}{V_{GS} - V_T}$ and why?

(b) Max Transconductance and Saturation

- $g_{m,max}$ observed: _____
- I_D at which g_m saturates: _____
- I_D for $g_{m,use} = 0.8 \times g_{m,max}$: _____

(c) Scaling Parameters

To obtain $g_{m,req} = 4 \times g_{m,use}$ while ensuring the same speed:

Question 3: CS Amplifier Design (g_m/I_D Approach)

Specifications: $A_v > 60$, $f_u = 100\text{MHz}$, $C_L = 1\text{pF}$, $V_{DD} = 1.8\text{V}$, $V^* = \frac{2I_D}{g_m} = 200\text{mV}$.

(a) Channel Length Selection

[Insert plot of g_{mr_o} vs V_{DS} for different L] Chosen L : _____ Output Swing Range: _____

(b) Process and Temperature Variations

[Insert g_{mr_o} vs V_{DS} plot for corners: tt, ff, ss and temps: -40, 25, 80, 125 °C]

(c) Design Calculations

- Calculated g_m :
- Calculated I_D :
- Calculated W :

(d) Transient Analysis and THD

[Insert annotated transient plots] THD for maximum input swing: _____

(e) AC Analysis

[Insert AC Response plots]

- Verified f_u :
- f_{-3dB} :
- AC Gain:

Question 4: Common Source Amplifier Variants

$R_L = 10\text{k}\Omega$, $V_{DD} = 1.8\text{V}$, $A_v > 5$, Overdrive = 200mV, $f_{min} = 100\text{Hz}$.

(a) Design Procedure (Resistive Load)

Total Power Consumption: _____

(b) Transient Simulation

[Insert transient plots for $v_{in} = 10 \sin(2\pi \cdot 1000t)\text{mV}$]

(c) AC Response

[Insert AC plots 1Hz to 1GHz] Unity Bandwidth f_u : _____

(d) PMOS Current Source Load

[Insert design procedure, Transient, and AC plots for $A_v > 15$]

(e) Cascode Amplifier Design

[Insert design procedure, Transient, and AC plots] Observed Gain: _____ Comparison with Hand Calculations:

(f) Comparison Table

Table 1: Comparison of Amplifier Topologies

Topology	Gain	Power	Output Swing	Remarks
Resistive Load				
PMOS Load				
Cascode				